#### **LASERS**

#### Applications:

Amplification: communications links (e.g. EFDA; avoids down-conversion)

Oscillator: frequency/distance reference, local oscillators, illuminators,

sources for fiber communications, CD/DVD players

Focused power: laser machining, weapons, laser fusion (pellet compression).

Peak > 1015W, average > 1kw

Note:  $10^{15}$  W in 10-micron spot  $\Rightarrow \bar{E} \cong 10^{14} \left[ Vm^{-1} \right] \left( 10^6 \text{ in H atom} \right)$ 

### **Basic Principles:**

Atoms and molecules in gases, impurities in solids, and electrons and holes in semiconductors have quantum states

A transition to a lower state emits a photon coherent with triggering photon

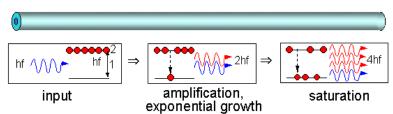
⇒ Exponential spatial amplification or, with internal reflection, oscillation

Amplification/lasing requires upper state population to exceed lower state

L19-1

### BASIC LASER AMPLIFIER PHYSICS

### **Basic Amplification Process:**



[Each • is a separate atom or molecule; need  $n_2 > n_1$  for amplification]

#### Basic Equations:

Amplification frequency:  $E_2 - E_1 = hf[J]$   $h = 6.625 \times 10^{-34} [Js]$ 

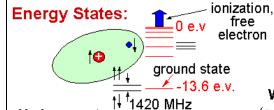
Photon increase (no pump):  $dn_2/dt = -[An_2 + B(n_2 - n_1)] \quad (n = \#/m^3)$ 

Wm<sup>-3</sup> emitted:  $P = hf d(n_2 - n_1)/dt [Jm^{-3}s^{-1}]$ 

A,B are the spontaneous and stimulated emission coefficients, respectively

L19-2

# **ENERGY STATES AND POPULATIONS**



#### States:



electronic (visible, UV) vibrational (visible) bending (IR) rotational (microwave)

#### Water vapor H2O

Hydrogen atom (Galactic arms) (e.g. water vapor masers around stars) (electric dipole transitions)

Chromium atoms in lattice (e.g. ruby), erbium atoms in glass

# Level Populations—Kinetic Temperature T<sub>k</sub>:

Thermal equilibrium dominated by collisions

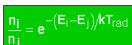
 $\Rightarrow$  Boltzmann distribution:

 $\frac{n_i}{n_i} = e^{-\left(E_i - E_j\right)/kT_k}$ 

Thermal equilibrium dominated by radiation

 $\Rightarrow$  Boltzmann distribution:

 $n_2 > n_1 \text{ if } T_{rad} < 0$ 



state energy E [J]



•••••• n<sub>1</sub>



L19-3

## **EINSTEIN "A" AND "B" COEFFICIENTS**

Rate Equation:  $dn_2/dt = -[An_2 + B(n_2 - n_1)]$  (n = #/m<sup>3</sup>, collisionless)

## **Einstein A Coefficient:**

Spontaneous emission:  $dn_i/dt = -A_in_i$  transitions  $m^{-3}s^{-1}$ 

 $A_{ij}$  between states i and j:  $A_{ij} = k^3 |D_{ij}|^2 2/3h\epsilon [s^{-1}]$ 

Dipole strength of transitions: D<sub>ii</sub> [Cm] is a quantum mechanical dipole

moment (electric or magnetic)

Decay time  $\tau_A = A^{-1}$  Note:  $\tau_A \propto \omega^{-3}$ , so "visible"  $\tau$ 's are short,

microwave τ's are long

#### B Coefficient:

Stimulated emission and absorption:  $B_{ij} = Ig_{ij}(f)|D_{ij}|^2N\pi^22/3h^2c\epsilon$  [s<sup>-1</sup>]  $g_{ij}(f)$ 

Proportional to radiation intensity I:  $I = |E|^2/2\eta_o \text{ [Wm}^2]$ 

Lorentzian line shape  $g_{ij}(f)$ :  $g_{ij}(f) = [2/\pi(\Delta f)]/[1 + 4(f - f_0)^2/(\Delta f)^2]$ 

 $g_{ij}(f)$  has unity integral:  $\int_{-\infty}^{\infty} g_{ij}(f) df = 1;$ 

[N is refractive index]  $g_{ij}(f)/g_o = 0.5 \text{ for } |f - f_o| = \Delta f/2$ 

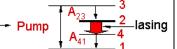
박 **!** 

# PUMPING LASERS

#### Three-Level Lasers:

Pump lasing \_lasing Pump levels 1,3 so  $n_1 \cong n_3$ Large  $A_{32}$  populates 2 so  $n_2 >> n_1 \cong n_3 \cong 0$ 

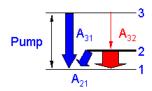
More levels sometimes used, e.g. to lower the pump frequency, or to utilize quantum states with larger A's -



#### Losses that Limit Short Wavelength Operation:

Key losses:  $(n_3A_{31} + n_2A_{21}hf_{31} [Pump Wm^{-1}]$ Recall  $A \propto \omega^3$ ; if  $B >> A \propto \omega^3$ , then

x-ray lasers need very high B (pump values)



L19-5

## LASER GAIN

### Fiber Amplifier Gain (if n atoms m<sup>-1</sup> in upper state; ~0 in lower):

dn/dt:  $= R - n(A + B) = R - (n/\tau_A) - I_{\#} \circ n$ (1)

[where R = Repopulation rate  $s^{-1}$  of n;  $l_{\#}$  = photons  $m^{-2}s^{-1}$ ;

 $\sigma$  = stimulated-emission cross-section [m<sup>2</sup>] atom <sup>-1</sup>]

Steady State: dn/dt = 0,  $\Rightarrow$  n = R $\tau_A$ /(1 +  $\tau_A$ I $_{\#}$  $\circlearrowleft$ ) = R $\tau_A$ /(1 + I $_{\#}$ /I $_{\#}$ sat) [I $_{\#}$ sat = 1/ $\tau_A$  $\circlearrowleft$ ] (2)

 $dl_{\#}/dz \cong l_{\#} \circ n$ , so that:  $l_{\#out} = l_{\#in} e^{\sigma nz} = l_{\#in} e^{gz}$  [gain g (nepers m<sup>-1</sup>)] When B>>A: (3)

Gain  $g \cong Gn = GR_{\tau_A}/(1 + I_\#I_{\#sat}) \rightarrow 0$  for  $I_\# >> I_{\#sat}$  [from (2,1)]

 $g \cong Gn < Gn_{max}$  [ $n_{max}$  is the number of amplifying atoms m<sup>-1</sup>]

G(nepers m<sup>-1</sup>):  $g = n\sigma = nB/I_{\#} = P_{pump}g_{jj}(f)|D|^2N\pi^22/3h^2c_8A$  for  $I_{\#} << I_{\#sat}$ (4)

[from 4,1,2,5, L-19-4]

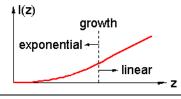
Where:  $P_{pump} [Wm^{-1}] > hf_p R \text{ and } n \cong R/[A(1 + I_{\#}/I_{\#sat})] \cong P_{pump}/[hf_p A(1 + I_{\#}/I_{\#sat})]$  (5)

 $G = I_{out}/I_{in} = e^{\int g(z)dz}$  where Laser Gain:

 $g(z) \cong \sigma P_{pump}/[hf_pA(1 + I_\#/I_{\#sat})]$ 

(Actually, net gain =  $g - \alpha$ ;

α represents losses)



L19-6

### LINE SHAPE

# Lorentzian Line Shape and Broadening Mechanisms:

Lorentzian line

 $g_{ii}(f) = [2/\pi(\Delta f)]/[1 + 4(f - f_0)^2/(\Delta f)^2]$ 

shape:

 $g_{ij}(f)$  has unity  $\int_{-\infty}^{\infty} g_{ij}(f) df = 1$ 

integral:

 $g_{ii}(f)/g_0 = 0.5 \text{ for } |f - f_0| = \Delta f/2$ 

Broadening

 $\Delta f_0 > 1/\tau_A = A \cong 10 \text{ MHz (minimum)}$ 

mechanisms:

linewidth); collisions, lattice interactions,

fields  $(\overline{E}, \overline{B})$ , Doppler

Homogeneous broadening:

Each atom has  $\Delta f \cong 4$  THz; a single frequency can drain G; e.g. EDFA's, most

solid-state and semiconductor lasers

innomogene broadening:

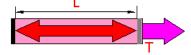
Inhomogeneous Each narrow-band atom shifted differently, e.g. HeNe

L19-7

 $\Delta \mathbf{f}$ 

## LASER OSCILLATORS

#### Laser Oscillation:



Amplifier: Assume length L, perfect mirrors at both ends;

Closed lossless amplifier must oscillate and saturate Gain m<sup>-1</sup> must exceed loss (threshold condition)

Modes: Resonances when  $\{m\lambda_m/2 = L\}$  (mirrors approx. short circuits)

 $\Rightarrow \lambda_m = 2L/m$ ,  $f_m = cm/2LN$  (N = index of refraction)

 $f_{i+1} - f_i = c/2LN \cong 10^8 Hz;$ 

 $\cong$  50 GHz for 0.5 mm semiconductor diodes

If linewidth  $\Delta f$  > line spacing, dominant line wins if saturation If linewidth  $\Delta f$  < line spacing, must tune cavity length to  $f_{\circ}$ 

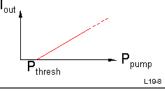
Source: Assume one mirror has power transmission coefficient T > 0

Gain  $\cong$  Loss:  $P_{+}(1-T)e^{2(g-\alpha)L} \ge P_{+}$ 

 $\Rightarrow$  two-pass gain  $e^{2(g-\alpha)L} \cong 1/(1-T)$ 

Output Limit: Usually  $T \cong losses = 1 - e^{-2(\alpha - g)L}$ ,

and I ≅ I<sub>sat</sub>



### **EXAMPLES OF LASERS**

### **Astrophysical Masers:**

Stellar pumped: Water vapor, OH, CO, etc.

Interstellar collisions: OH, etc.

#### Gas Lasers:

Ammonia (23 GHz): "Pumped" by diverting molecules in ground state

CO<sub>2</sub>, HeNe: Pumped by electrical discharges that form energetic plasmas

Chemical: Chemical combustion yields upper-state excess

#### Externally Pumped Solid-State Lasers

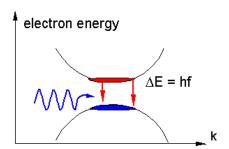
Ruby: Pumped by flash lamps, etc. EDFA: Pumped by semiconductor lasers

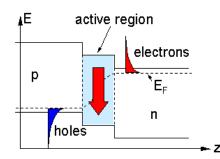
L19-9

# **EXAMPLES OF LASERS (2)**

### Electronically Pumped Solid-State Lasers:

Forward biased GaAs p-n junction injects carriers into conduction band Compact (grain of sand), ~50 percent efficiency, >100 W/cm² for arrays, 1 mW/micron² for diodes (1-1000 mW typical)





L19-10